

# **BAT54CV**

# Two Schottky barrier double diodes Rev. 3 — 15 November 2010

Product data sheet

## **Product profile**

## 1.1 General description

Two planar Schottky barrier double diodes with common cathodes and an integrated guard ring for stress protection encapsulated in a SOT666 ultra small and flat lead Surface-Mounted Device (SMD) plastic package.

#### 1.2 Features and benefits

- Low forward voltage
- Low capacitance
- AEC-Q101 qualified
- Ultra small and flat lead SMD plastic package
- Excellent coplanarity and improved thermal behavior

## 1.3 Applications

- Ultra high-speed switching
- Voltage clamping
- Line termination
- Reverse polarity protection

## 1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per diode						
I <sub>F</sub>	forward current		-	-	200	mA
$V_R$	reverse voltage		-	-	30	V
V <sub>F</sub> forward voltage	forward voltage		[1]			
		$I_F = 0.1 \text{ mA}$	-	-	240	mV
		$I_F = 1 \text{ mA}$	-	-	320	mV
		$I_F = 10 \text{ mA}$	-	-	400	mV
		$I_F = 30 \text{ mA}$	-	-	500	mV
		I <sub>F</sub> = 100 mA	-	-	800	mV

<sup>[1]</sup> Pulse test:  $t_p \le 300~\mu s;~\delta \le 0.02.$ 



## Two Schottky barrier double diodes

# 2. Pinning information

Table 2. Pinning

Table 2.	Pinning		
Pin	Description	Simplified outline	Graphic symbol
1	anode (diode 1)		
2	anode (diode 2)	6 5 4	6 5 4
3	common cathode (diode 3, 4)		
4	anode (diode 3)		
5	anode (diode 4)	1 2 3	
6	common cathode (diode 1, 2)	1 2 3	1 2 3 sym057

# 3. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
BAT54CV	-	plastic surface-mounted package; 6 leads	SOT666

# 4. Marking

Table 4. Marking codes

Type number	Marking code
BAT54CV	C5

# 5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
Per diode					
$V_R$	reverse voltage		-	30	V
I <sub>F</sub>	forward current		-	200	mA
I <sub>FRM</sub>	repetitive peak forward current	$t_p \leq 10 \text{ ms; } \delta \leq 0.5$	-	0.85	А
I <sub>FSM</sub>	non-repetitive peak forward current	square wave; t <sub>p</sub> = 8.3 ms	[1] -	2	A

#### Two Schottky barrier double diodes

 Table 5.
 Limiting values ... continued

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
Per device	e, one diode loaded				
P <sub>tot</sub> total power dissipation		$T_{amb} \le 25  ^{\circ}C$	[2]		
			[3] _	350	mW
			[4] _	420	mW
Tj	junction temperature		-	125	°C
T <sub>amb</sub>	ambient temperature		-65	+125	°C
T <sub>stg</sub>	storage temperature		-65	+150	°C

<sup>[1]</sup>  $T_i = 25$  °C prior to surge.

## 6. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per device	, one diode loaded					
$R_{th(j-a)}$	thermal resistance from	in free air	[1][2]			
	junction to ambient		[3] _	-	360	K/W
			[4] _	-	300	K/W
R <sub>th(j-sp)</sub>	thermal resistance from junction to solder point		<u>[5]</u> _	-	175	K/W

<sup>[1]</sup> For Schottky barrier diodes thermal runaway has to be considered, as in some applications the reverse power losses P<sub>R</sub> are a significant part of the total power losses.

<sup>[2]</sup> Reflow soldering is the only recommended soldering method.

<sup>[3]</sup> Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

<sup>[4]</sup> Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm<sup>2</sup>.

<sup>[2]</sup> Reflow soldering is the only recommended soldering method.

<sup>[3]</sup> Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

<sup>[4]</sup> Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm<sup>2</sup>.

<sup>[5]</sup> Soldering point of cathode tab.

## Two Schottky barrier double diodes

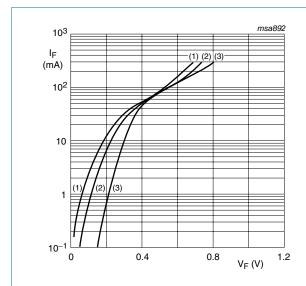
## 7. Characteristics

Table 7. Characteristics

 $T_{amb} = 25$  °C unless otherwise specified.

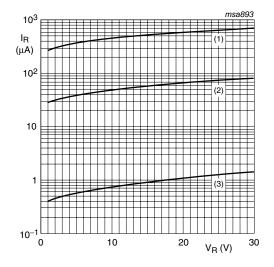
$\begin{tabular}{l lllllllllllllllllllllllllllllllllll$	-	240	mV
$I_F = 0.1 \text{ mA}$ $I_F = 1 \text{ mA}$	-	240	mV
$I_F = 1 \text{ mA}$	-	240	m\/
<u>'</u>			1117
$I_F = 10 \text{ mA}$	-	320	mV
	-	400	mV
$I_F = 30 \text{ mA}$	-	500	mV
$I_F = 100 \text{ mA}$	-	800	mV
$I_R$ reverse current $V_R = 25 \text{ V}$ -	-	2	μΑ
$C_d$ diode capacitance $V_R = 1 V$ ; $f = 1 MHz$ -	_	10	pF

<sup>[1]</sup> Pulse test:  $t_p \le 300~\mu s;~\delta \le 0.02.$ 



- (1)  $T_{amb} = 125 \, ^{\circ}C$
- (2)  $T_{amb} = 85 \, ^{\circ}C$
- (3)  $T_{amb} = 25 \, ^{\circ}C$

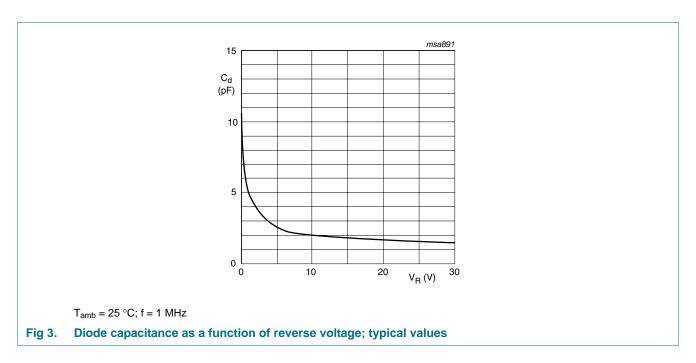
Fig 1. Forward current as a function of forward voltage; typical values



- (1)  $T_{amb} = 125 \, ^{\circ}C$
- (2)  $T_{amb} = 85 \, ^{\circ}C$
- (3)  $T_{amb} = 25 \, ^{\circ}C$

Fig 2. Reverse current as a function of reverse voltage; typical values

#### Two Schottky barrier double diodes

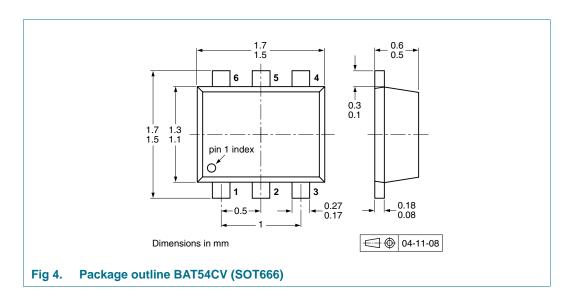


## 8. Test information

## 8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101 - Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

## 9. Package outline



## Two Schottky barrier double diodes

## 10. Packing information

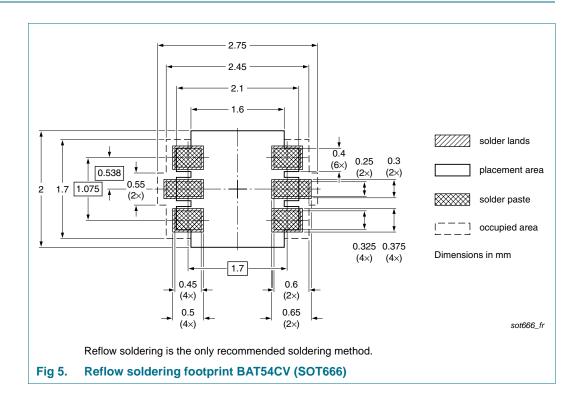
Table 8. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number	Package	Description	Packing quantity
			4000
BAT54CV	SOT666	4 mm pitch, 8 mm tape and reel	-115

<sup>[1]</sup> For further information and the availability of packing methods, see Section 14.

## 11. Soldering



## Two Schottky barrier double diodes

# 12. Revision history

## Table 9. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BAT54CV v.3	20101115	Product data sheet	-	BAT54CV_2
Modifications:	<ul> <li>Table 1 "Quick</li> <li>Table 5 "Limitin</li> <li>Table 6 "Therm</li> <li>Figure 4: super</li> <li>Section 8 "Test</li> <li>Section 11 "Sol</li> </ul>	atures and benefits": amer reference data": updated. g values": P <sub>tot</sub> amended. al characteristics": R <sub>th(j-a)</sub> a seded by minimized outline information": added. dering": added. gal information": updated.	amended, R <sub>th(j-sp)</sub> add	ed.
BAT54CV_2	20100115	Objective data sheet	-	BAT54CV_1
BAT54CV_1	20040922	Objective data sheet	-	-

#### Two Schottky barrier double diodes

## 13. Legal information

#### 13.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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BAT54CV

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**Quick reference data** — The Quick reference data is an extract of the product data given in the Limiting values and Characteristics sections of this document, and as such is not complete, exhaustive or legally binding.

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